

### KSC2690/2690A

# **Audio Frequency** High Frequency Power Amplifier • Complement to KSA1220/KSA1220A



## **NPN Epitaxial Silicon Transistor**

#### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage		
	: KSC2690	120	V
	: KSC2690A	160	V
$V_{CEO}$	Collector- Emitter Voltage		
	: KSC2690	120	V
	: KSC2690A	160	V
$V_{EBO}$	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current (DC)	1.2	Α
I <sub>CP</sub>	*Collector Current (Pulse)	2.5	А
	Base Current(DC)	0.3	А
I <sub>B</sub>	Collector Dissipation (T <sub>a</sub> =25°C)	1.2	W
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	20	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

<sup>\*</sup> PW≤10ms, Duty Cycle≤50%

### **Electrical Characteristics** $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 120V, I_{E} = 0$			1	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 3V, I_{C} = 0$			1	μΑ
h <sub>FE1</sub>	* DC Current Gain	$V_{CE} = 5V$ , $I_C = 5mA$	35	105		
$h_{FE2}$		$V_{CE} = 5V, I_{C} = 0.3A$	60	140	320	
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	$I_C = 1A, I_B = 0.2A$		0.4	0.7	V
V <sub>BE</sub> (sat)	* Base-Emitter Saturation Voltage	$I_C = 1A, I_B = 0.2A$		1	1.3	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 5V, I_{C} = 0.2A$		155		MHz
C <sub>ob</sub>	Output Capacitance	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$		19		pF

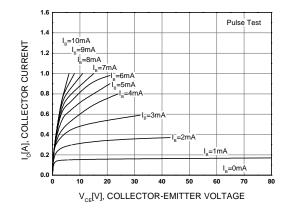
<sup>\*</sup> Pulse Test: PW≤350μs, Duty Cycle≤2% Pulsed

### **h**<sub>FE</sub> Classificntion

Classification	R	0	Υ
h <sub>FE2</sub>	60 ~ 120	100 ~ 200	160 ~ 320

©2000 Fairchild Semiconductor International

### **Typical Characteristics**



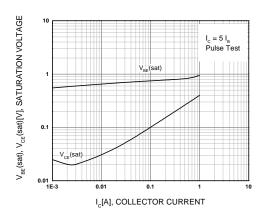
1000 V<sub>CE</sub> = 5V Pulse Test.

Pulse Test.

1000 100 100 1 1 1 100 1 1 1 100 1 1 100 1

Figure 1. Static Characteristic

Figure 2. DC current Gain



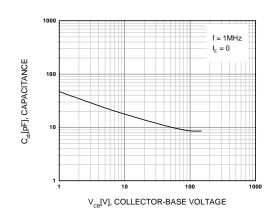
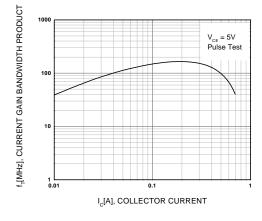


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

Figure 4. Collector Output Capacitance



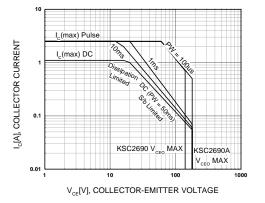
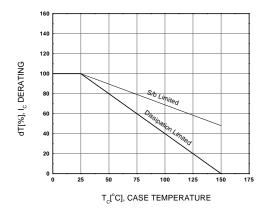


Figure 5. Current Gain Bandwidth Product

Figure 6. Safe Operating Area

©2000 Fairchild Semiconductor International Rev. A, February 2000

# **Typical Characteristics** (Continued)



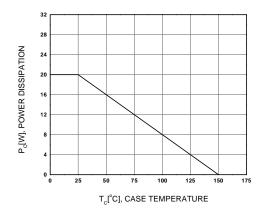


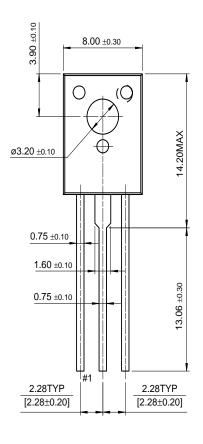
Figure 7. Derating Curve of Safe Operating Areas

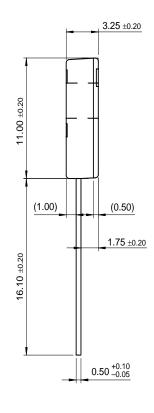
Figure 8. Power Derating

KSC2690/2690A

## **Package Demensions**

TO-126





Dimensions in Millimeters

#### **TRADEMARKS**

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

FACT™ QFET™ FACT Quiet Series™ QS™

FAST<sup>®</sup> Quiet Series<sup>™</sup> SuperSOT<sup>™</sup>-3 GTO<sup>™</sup> SuperSOT<sup>™</sup>-6

#### **DISCLAIMER**

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

#### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR INTERNATIONAL.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

#### PRODUCT STATUS DEFINITIONS

#### **Definition of Terms**

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

©2000 Fairchild Semiconductor International Rev. E

## **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

onsemi

KSC2690YSTU